Lattice Semiconductor Corporation - LC4128ZC-75TN100I Datasheet

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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Active
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	1.7V ~ 1.9V
Number of Logic Elements/Blocks	8
Number of Macrocells	128
Number of Gates	-
Number of I/O	64
Operating Temperature	-40°C ~ 105°C (TJ)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-TQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lc4128zc-75tn100i

Table 5. Product Term Expansion Capability

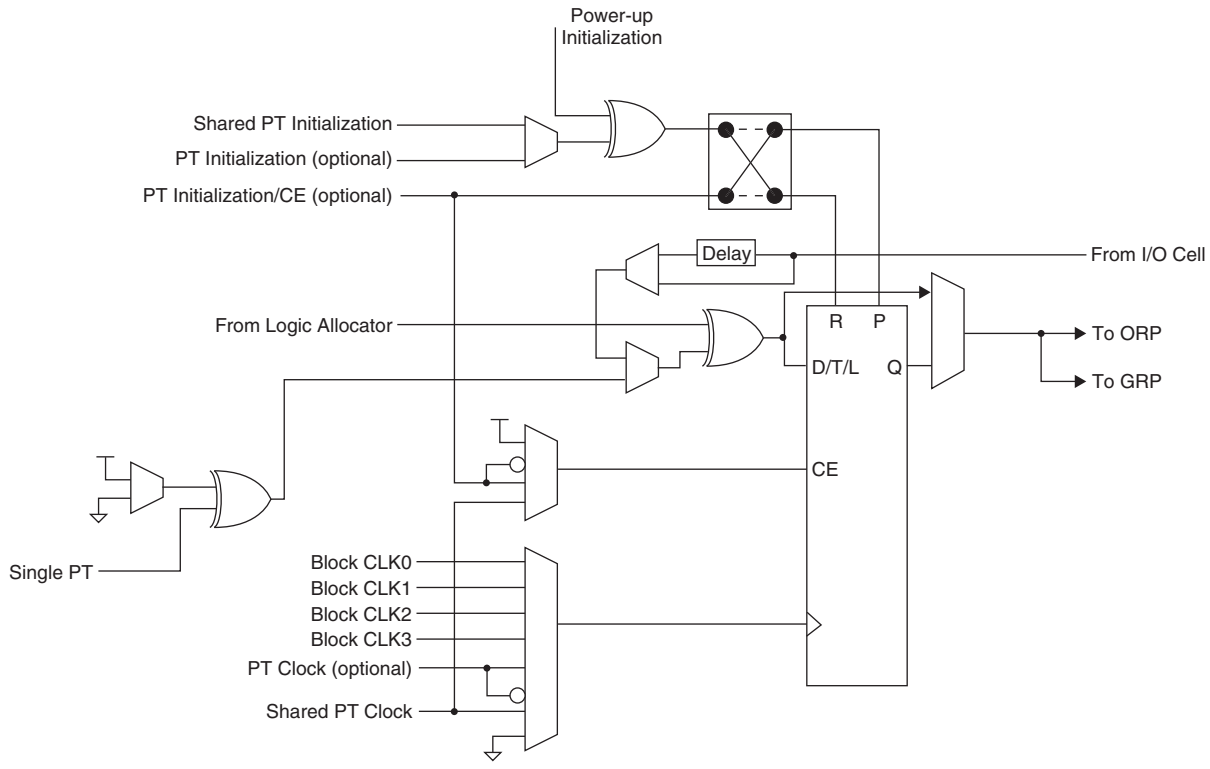
Expansion Chains	Macrocells Associated with Expansion Chain (with Wrap Around)	Max PT/ Macrocell
Chain-0	M0 M4 M8 M12 M0	75
Chain-1	M1 M5 M9 M13 M1	80
Chain-2	M2 M6 M10 M14 M2	75
Chain-3	M3 M7 M11 M15 M3	70

Every time the super cluster allocator is used, there is an incremental delay of t_{EXP}. When the super cluster allocator is used, all destinations other than the one being steered to, are given the value of ground (i.e., if the super cluster is steered to M (n+4), then M (n) is ground).

Macrocell

The 16 macrocells in the GLB are driven by the 16 outputs from the logic allocator. Each macrocell contains a programmable XOR gate, a programmable register/latch, along with routing for the logic and control functions. Figure 5 shows a graphical representation of the macrocell. The macrocells feed the ORP and GRP. A direct input from the I/O cell allows designers to use the macrocell to construct high-speed input registers. A programmable delay in this path allows designers to choose between the fastest possible set-up time and zero hold time.

Figure 5. Macrocell



Enhanced Clock Multiplexer

The clock input to the flip-flop can select any of the four block clocks along with the shared PT clock, and true and complement forms of the optional individual term clock. An 8:1 multiplexer structure is used to select the clock. The eight sources for the clock multiplexer are as follows:

- Block CLK0
- Block CLK1

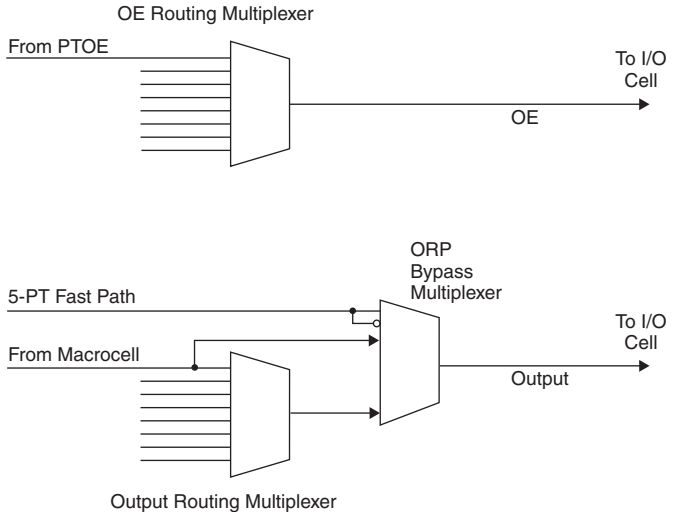
Output Routing Pool (ORP)

The Output Routing Pool allows macrocell outputs to be connected to any of several I/O cells within an I/O block. This provides greater flexibility in determining the pinout and allows design changes to occur without affecting the pinout. The output routing pool also provides a parallel capability for routing macrocell-level OE product terms. This allows the OE product term to follow the macrocell output as it is switched between I/O cells. Additionally, the output routing pool allows the macrocell output or true and complement forms of the 5-PT bypass signal to bypass the output routing multiplexers and feed the I/O cell directly. The enhanced ORP of the ispMACH 4000 family consists of the following elements:

- Output Routing Multiplexers
- OE Routing Multiplexers
- Output Routing Pool Bypass Multiplexers

Figure 7 shows the structure of the ORP from the I/O cell perspective. This is referred to as an ORP slice. Each ORP has as many ORP slices as there are I/O cells in the corresponding I/O block.

Figure 7. ORP Slice



Output Routing Multiplexers

The details of connections between the macrocells and the I/O cells vary across devices and within a device dependent on the maximum number of I/Os available. Tables 5-9 provide the connection details.

Table 6. ORP Combinations for I/O Blocks with 8 I/Os

I/O Cell	Available Macrocells
I/O 0	M0, M1, M2, M3, M4, M5, M6, M7
I/O 1	M2, M3, M4, M5, M6, M7, M8, M9
I/O 2	M4, M5, M6, M7, M8, M9, M10, M11
I/O 3	M6, M7, M8, M9, M10, M11, M12, M13
I/O 4	M8, M9, M10, M11, M12, M13, M14, M15
I/O 5	M10, M11, M12, M13, M14, M15, M0, M1
I/O 6	M12, M13, M14, M15, M0, M1, M2, M3
I/O 7	M14, M15, M0, M1, M2, M3, M4, M5

Table 7. ORP Combinations for I/O Blocks with 16 I/Os

I/O Cell	Available Macrocells
I/O 0	M0, M1, M2, M3, M4, M5, M6, M7
I/O 1	M1, M2, M3, M4, M5, M6, M7, M8
I/O 2	M2, M3, M4, M5, M6, M7, M8, M9
I/O 3	M3, M4, M5, M6, M7, M8, M9, M10
I/O 4	M4, M5, M6, M7, M8, M9, M10, M11
I/O 5	M5, M6, M7, M8, M9, M10, M11, M12
I/O 6	M6, M7, M8, M9, M10, M11, M12, M13
I/O 7	M7, M8, M9, M10, M11, M12, M13, M14
I/O 8	M8, M9, M10, M11, M12, M13, M14, M15
I/O 9	M9, M10, M11, M12, M13, M14, M15, M0
I/O 10	M10, M11, M12, M13, M14, M15, M0, M1
I/O 11	M11, M12, M13, M14, M15, M0, M1, M2
I/O 12	M12, M13, M14, M15, M0, M1, M2, M3
I/O 13	M13, M14, M15, M0, M1, M2, M3, M4
I/O 14	M14, M15, M0, M1, M2, M3, M4, M5
I/O 15	M15, M0, M1, M2, M3, M4, M5, M6

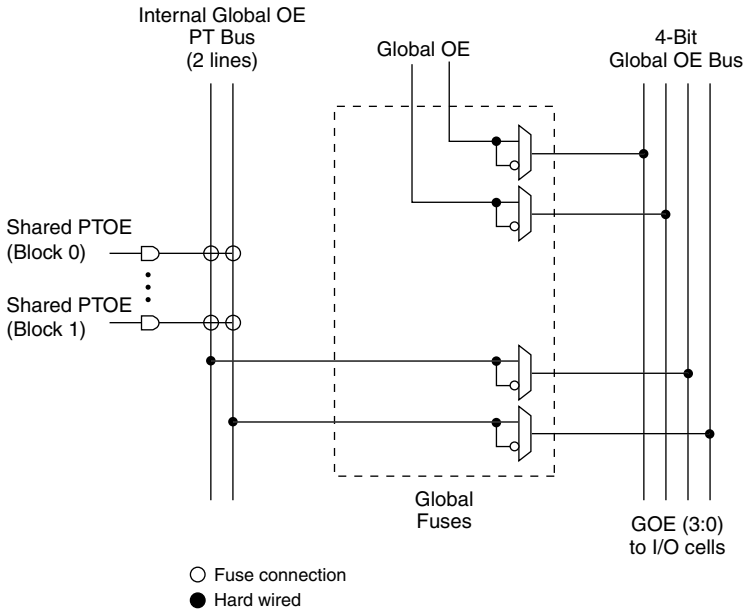
Table 8. ORP Combinations for I/O Blocks with 4 I/Os

I/O Cell	Available Macrocells
I/O 0	M0, M1, M2, M3, M4, M5, M6, M7
I/O 1	M4, M5, M6, M7, M8, M9, M10, M11
I/O 2	M8, M9, M10, M11, M12, M13, M14, M15
I/O 3	M12, M13, M14, M15, M0, M1, M2, M3

Table 9. ORP Combinations for I/O Blocks with 10 I/Os

I/O Cell	Available Macrocells
I/O 0	M0, M1, M2, M3, M4, M5, M6, M7
I/O 1	M2, M3, M4, M5, M6, M7, M8, M9
I/O 2	M4, M5, M6, M7, M8, M9, M10, M11
I/O 3	M6, M7, M8, M9, M10, M11, M12, M13
I/O 4	M8, M9, M10, M11, M12, M13, M14, M15
I/O 5	M10, M11, M12, M13, M14, M15, M0, M1
I/O 6	M12, M13, M14, M15, M0, M1, M2, M3
I/O 7	M14, M15, M0, M1, M2, M3, M4, M5
I/O 8	M2, M3, M4, M5, M6, M7, M8, M9
I/O 9	M10, M11, M12, M13, M14, M15, M0, M1

Figure 10. Global OE Generation for ispMACH 4032



Zero Power/Low Power and Power Management

The ispMACH 4000 family is designed with high speed low power design techniques to offer both high speed and low power. With an advanced E^2 low power cell and non sense-amplifier design approach (full CMOS logic approach), the ispMACH 4000 family offers SuperFAST pin-to-pin speeds, while simultaneously delivering low standby power without needing any “turbo bits” or other power management schemes associated with a traditional sense-amplifier approach.

The zero power ispMACH 4000Z is based on the 1.8V ispMACH 4000C family. With innovative circuit design changes, the ispMACH 4000Z family is able to achieve the industry’s “lowest static power”.

IEEE 1149.1-Compliant Boundary Scan Testability

All ispMACH 4000 devices have boundary scan cells and are compliant to the IEEE 1149.1 standard. This allows functional testing of the circuit board on which the device is mounted through a serial scan path that can access all critical logic notes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test node data to be captured and shifted out for verification. In addition, these devices can be linked into a board-level serial scan path for more board-level testing. The test access port operates with an LVCMOS interface that corresponds to the power supply voltage.

I/O Quick Configuration

To facilitate the most efficient board test, the physical nature of the I/O cells must be set before running any continuity tests. As these tests are fast, by nature, the overhead and time that is required for configuration of the I/Os’ physical nature should be minimal so that board test time is minimized. The ispMACH 4000 family of devices allows this by offering the user the ability to quickly configure the physical nature of the I/O cells. This quick configuration takes milliseconds to complete, whereas it takes seconds for the entire device to be programmed. Lattice's ispVM® System programming software can either perform the quick configuration through the PC parallel port, or can generate the ATE or test vectors necessary for a third-party test system.

Absolute Maximum Ratings[1, 2, 3]

	ispMACH 4000C/Z (1.8V)	ispMACH 4000B (2.5V)	ispMACH 4000V (3.3V)
Supply Voltage (V_{CC})	-0.5 to 2.5V	-0.5 to 5.5V	-0.5 to 5.5V
Output Supply Voltage (V_{CCO})	-0.5 to 4.5V	-0.5 to 4.5V	-0.5 to 4.5V
Input or I/O Tristate Voltage Applied[4, 5]	-0.5 to 5.5V	-0.5 to 5.5V	-0.5 to 5.5V
Storage Temperature	-65 to 150°C	-65 to 150°C	-65 to 150°C
Junction Temperature (T_j) with Power Applied	-55 to 150°C	-55 to 150°C	-55 to 150°C

1. Stress above those listed under the “Absolute Maximum Ratings” may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.
2. Compliance with Lattice Thermal Management document is required.
3. All voltages referenced to GND.
4. Undershoot of -2V and overshoot of (V_{IH} (MAX) + 2V), up to a total pin voltage of 6.0V, is permitted for a duration of < 20ns.
5. Maximum of 64 I/Os per device with VIN > 3.6V is allowed.

Recommended Operating Conditions

Symbol	Parameter		Min.	Max.	Units
V_{CC}	Supply Voltage for 1.8V Devices	ispMACH 4000C	1.65	1.95	V
		ispMACH 4000Z	1.7	1.9	V
		ispMACH 4000Z, Extended Functional Voltage Operation	1.6[1, 2]	1.9	V
	Supply Voltage for 2.5V Devices		2.3	2.7	V
	Supply Voltage for 3.3V Devices		3.0	3.6	V
T_j	Junction Temperature (Commercial)		0	90	C
	Junction Temperature (Industrial)		-40	105	C
	Junction Temperature (Extended)		-40	130	C

1. Devices operating at 1.6V can expect performance degradation up to 35%.
2. Applicable for devices with 2004 date codes and later. Contact factory for ordering instructions.

Erase Reprogram Specifications

Parameter	Min.	Max.	Units
Erase/Reprogram Cycle	1,000	—	Cycles

Note: Valid over commercial temperature range.

Hot Socketing Characteristics[1,2,3]

Symbol	Parameter	Condition	Min.	Typ.	Max.	Units
I_{DK}	Input or I/O Leakage Current	$0 \le V_{IN} \le 3.0V$, Tj = 105°C	—	±30	±150	µA
		$0 \le V_{IN} \le 3.0V$, Tj = 130°C	—	±30	±200	µA

1. Insensitive to sequence of V_{CC} or V_{CCO}. However, assumes monotonic rise/fall rates for V_{CC} and V_{CCO}, provided (V_{IN} - V_{CCO}) ≤ 3.6V.
2. $0 < V_{CC} < V_{CC}$ (MAX), $0 < V_{CCO} < V_{CCO}$ (MAX).
3. I_{DK} is additive to I_{PU}, I_{PD} or I_{BH}. Device defaults to pull-up until fuse circuitry is active.

I/O DC Electrical Characteristics

Over Recommended Operating Conditions

Standard	V_{IL}		V_{IH}		V_{OL} Max (V)	V_{OH} Min (V)	I_{OL}[1] (mA)	I_{OH}[1] (mA)
	Min (V)	Max (V)	Min (V)	Max (V)				
LVTTL	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 3.3	-0.3	0.80	2.0	5.5	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 2.5	-0.3	0.70	1.70	3.6	0.40	V_{CCO} - 0.40	8.0	-4.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.8 (4000V/B)	-0.3	0.63	1.17	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
LVCMOS 1.8 (4000C/Z)	-0.3	0.35 * V_{CC}	0.65 * V_{CC}	3.6	0.40	V_{CCO} - 0.45	2.0	-2.0
					0.20	V_{CCO} - 0.20	0.1	-0.1
PCI 3.3 (4000V/B)	-0.3	1.08	1.5	5.5	0.1 V_{CCO}	0.9 V_{CCO}	1.5	-0.5
PCI 3.3 (4000C/Z)	-0.3	0.3 * 3.3 * (V_{CC} / 1.8)	0.5 * 3.3 * (V_{CC} / 1.8)	5.5	0.1 V_{CCO}	0.9 V_{CCO}	1.5	-0.5

1. The average DC current drawn by I/Os between adjacent bank GND connections, or between the last GND in an I/O bank and the end of the I/O bank, as shown in the logic signals connection table, shall not exceed *n**8mA. Where *n* is the number of I/Os between bank GND connections or between the last GND in a bank and the end of a bank.

ispMACH 4000V/B/C External Switching Characteristics

Over Recommended Operating Conditions

Parameter	Description[1, 2, 3]	-25		-27		-3		-35		Units
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
t_{PD}	5-PT bypass combinatorial propagation delay	—	2.5	—	2.7	—	3.0	—	3.5	ns
t_{PD_MC}	20-PT combinatorial propagation delay through macrocell	—	3.2	—	3.5	—	3.8	—	4.2	ns
t_S	GLB register setup time before clock	1.8	—	1.8	—	2.0	—	2.0	—	ns
t_{ST}	GLB register setup time before clock with T-type register	2.0	—	2.0	—	2.2	—	2.2	—	ns
t_{SIR}	GLB register setup time before clock, input register path	0.7	—	1.0	—	1.0	—	1.0	—	ns
t_{SIRZ}	GLB register setup time before clock with zero hold	1.7	—	2.0	—	2.0	—	2.0	—	ns
t_H	GLB register hold time after clock	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HT}	GLB register hold time after clock with T-type register	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	GLB register hold time after clock, input register path	0.9	—	1.0	—	1.0	—	1.0	—	ns
t_{HIRZ}	GLB register hold time after clock, input register path with zero hold	0.0	—	0.0	—	0.0	—	0.0	—	ns
t_{CO}	GLB register clock-to-output delay	—	2.2	—	2.7	—	2.7	—	2.7	ns
t_R	External reset pin to output delay	—	3.5	—	4.0	—	4.4	—	4.5	ns
t_{RW}	External reset pulse duration	1.5	—	1.5	—	1.5	—	1.5	-	ns
$t_{PTOE/DIS}$	Input to output local product term output enable/disable	—	4.0	—	4.5	—	5.0	—	5.5	ns
$t_{GPTOE/DIS}$	Input to output global product term output enable/disable	—	5.0	—	6.5	—	8.0	—	8.0	ns
$t_{GOE/DIS}$	Global OE input to output enable/disable	—	3.0	—	3.5	—	4.0	—	4.5	ns
t_{CW}	Global clock width, high or low	1.1	—	1.3	—	1.3	—	1.3	—	ns
t_{GW}	Global gate width low (for low transparent) or high (for high transparent)	1.1	—	1.3	—	1.3	—	1.3	—	ns
t_{WIR}	Input register clock width, high or low	1.1	—	1.3	—	1.3	—	1.3	—	ns
f_{MAX}[4]	Clock frequency with internal feedback	—	400	—	333	—	322	—	322	MHz
f_{MAX} (Ext.)	Clock frequency with external feedback, $[1/ (t_S + t_{CO})]$	—	250	—	222	—	212	—	212	MHz

1. Timing numbers are based on default LVCMOS 1.8 I/O buffers. Use timing adjusters provided to calculate other standards.
2. Measured using standard switching circuit, assuming GRP loading of 1 and 1 output switching.
3. Pulse widths and clock widths less than minimum will cause unknown behavior.
4. Standard 16-bit counter using GRP feedback.

Timing v.3.2

ispMACH 4000Z External Switching Characteristics

Over Recommended Operating Conditions

Parameter	Description[1, 2, 3]	-35		-37		-42		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{PD}	5-PT bypass combinatorial propagation delay	—	3.5	—	3.7	—	4.2	ns
t_{PD_MC}	20-PT combinatorial propagation delay through macrocell	—	4.4	—	4.7	—	5.7	ns
t_S	GLB register setup time before clock	2.2	—	2.5	—	2.7	—	ns
t_{ST}	GLB register setup time before clock with T-type register	2.4	—	2.7	—	2.9	—	ns
t_{SIR}	GLB register setup time before clock, input register path	1.0	—	1.1	—	1.3	—	ns
t_{SIRZ}	GLB register setup time before clock with zero hold	2.0	—	2.1	—	2.6	—	ns
t_H	GLB register hold time after clock	0.0	—	0.0	—	0.0	—	ns
t_{HT}	GLB register hold time after clock with T-type register	0.0	—	0.0	—	0.0	—	ns
t_{HIR}	GLB register hold time after clock, input register path	1.0	—	1.0	—	1.3	—	ns
t_{HIRZ}	GLB register hold time after clock, input register path with zero hold	0.0	—	0.0	—	0.0	—	ns
t_{CO}	GLB register clock-to-output delay	—	3.0	—	3.2	—	3.5	ns
t_R	External reset pin to output delay	—	5.0	—	6.0	—	7.3	ns
t_{RW}	External reset pulse duration	1.5	—	1.7	—	2.0	—	ns
$t_{PTOE/DIS}$	Input to output local product term output enable/disable	—	7.0	—	8.0	—	8.0	ns
$t_{GPTOE/DIS}$	Input to output global product term output enable/disable	—	6.5	—	7.0	—	8.0	ns
$t_{GOE/DIS}$	Global OE input to output enable/disable	—	4.5	—	4.5	—	4.8	ns
t_{CW}	Global clock width, high or low	1.0	—	1.5	—	1.8	—	ns
t_{GW}	Global gate width low (for low transparent) or high (for high transparent)	1.0	—	1.5	—	1.8	—	ns
t_{WIR}	Input register clock width, high or low	1.0	—	1.5	—	1.8	—	ns
f_{MAX}[4]	Clock frequency with internal feedback	—	267	—	250	—	220	MHz
f_{MAX} (Ext.)	clock frequency with external feedback, $[1 / (t_S + t_{CO})]$	—	192	—	175	—	161	MHz

1. Timing numbers are based on default LVCMOS 1.8 I/O buffers. Use timing adjusters provided to calculate other standards.

Timing v.2.2

2. Measured using standard switching GRP loading of 1 and 1 output switching.
3. Pulse widths and clock widths less than minimum will cause unknown behavior.
4. Standard 16-bit counter using GRP feedback.

ispMACH 4000V/B/C Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	-2.5		-2.7		-3		-3.5		Units
In/Out Delays										
t_{IN}	Input Buffer Delay	—	0.60	—	0.60	—	0.70	—	0.70	ns
t_{GOE}	Global OE Pin Delay	—	2.04	—	2.54	—	3.04	—	3.54	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	0.78	—	1.28	—	1.28	—	1.28	ns
t_{BUF}	Delay through Output Buffer	—	0.85	—	0.85	—	0.85	—	0.85	ns
t_{EN}	Output Enable Time	—	0.96	—	0.96	—	0.96	—	0.96	ns
t_{DIS}	Output Disable Time	—	0.96	—	0.96	—	0.96	—	0.96	ns
Routing/GLB Delays										
t_{ROUTE}	Delay through GRP	—	0.61	—	0.81	—	1.01	—	1.01	ns
t_{MCELL}	Macrocell Delay	—	0.45	—	0.55	—	0.55	—	0.65	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.11	—	0.31	—	0.31	—	0.31	ns
t_{FBK}	Internal Feedback Delay	—	0.00	—	0.00	—	0.00	—	0.00	ns
t_{PDb}	5-PT Bypass Propagation Delay	—	0.44	—	0.44	—	0.44	—	0.94	ns
t_{PDi}	Macrocell Propagation Delay	—	0.64	—	0.64	—	0.64	—	0.94	ns
Register/Latch Delays										
t_S	D-Register Setup Time (Global Clock)	0.92	—	1.12	—	1.02	—	0.92	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32	—	1.32	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	1.12	—	1.32	—	1.22	—	1.12	—	ns
t_{ST_PT}	T-Register Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32	—	1.32	—	ns
t_H	D-Register Hold Time	0.88	—	0.68	—	0.98	—	1.08	—	ns
t_{HT}	T-Register Hold Time	0.88	—	0.68	—	0.98	—	1.08	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	0.82	—	1.37	—	1.27	—	1.27	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	0.88	—	0.63	—	0.73	—	0.73	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.88	—	0.63	—	0.73	—	0.73	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.52	—	0.52	—	0.52	—	0.52	ns
t_{CES}	Clock Enable Setup Time	2.25	—	2.25	—	2.25	—	2.25	—	ns
t_{CEH}	Clock Enable Hold Time	1.88	—	1.88	—	1.88	—	1.88	—	ns
t_{SL}	Latch Setup Time (Global Clock)	0.92	—	1.12	—	1.02	—	0.92	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.42	—	1.32	—	1.32	—	1.32	—	ns
t_{HL}	Latch Hold Time	1.17	—	1.17	—	1.17	—	1.17	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.33	—	0.33	—	0.33	—	0.33	ns

ispMACH 4000V/B/C Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description	-2.5		-2.7		-3		-3.5		Units
t_{PDLi}	Propagation Delay through Transparent Latch to Output/ Feedback MUX	—	0.25	—	0.25	—	0.25	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	0.28	—	0.28	—	0.28	—	0.28	—	ns
t_{SRR}	Asynchronous Reset or Set Recovery Time	1.67	—	1.67	—	1.67	—	1.67	—	ns
Control Delays										
t_{BCLK}	GLB PT Clock Delay	—	1.12	—	1.12	—	1.12	—	1.12	ns
t_{PTCLK}	Macrocell PT Clock Delay	—	0.87	—	0.87	—	0.87	—	0.87	ns
t_{BSR}	Block PT Set/Reset Delay	—	1.83	—	1.83	—	1.83	—	1.83	ns
t_{PTSR}	Macrocell PT Set/Reset Delay	—	1.11	—	1.41	—	1.51	—	1.61	ns
t_{GPTOE}	Global PT OE Delay	—	2.83	—	4.13	—	5.33	—	5.33	ns
t_{PTOE}	Macrocell PT OE Delay	—	1.83	—	2.13	—	2.33	—	2.83	ns

Timing v.3.2

Note: Internal Timing Parameters are not tested and are for reference only. Refer to the Timing Model in this data sheet for further details.

ispMACH 4000Z Internal Timing Parameters

Over Recommended Operating Conditions

Parameter	Description	-35		-37		-42		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
In/Out Delays								
t_{IN}	Input Buffer Delay	—	0.75	—	0.80	—	0.75	ns
t_{GOE}	Global OE Pin Delay	—	2.25	—	2.25	—	2.30	ns
t_{GCLK_IN}	Global Clock Input Buffer Delay	—	1.60	—	1.60	—	1.95	ns
t_{BUF}	Delay through Output Buffer	—	0.75	—	0.90	—	0.90	ns
t_{EN}	Output Enable Time	—	2.25	—	2.25	—	2.50	ns
t_{DIS}	Output Disable Time	—	1.35	—	1.35	—	2.50	ns
Routing/GLB Delays								
t_{ROUTE}	Delay through GRP	—	1.60	—	1.60	—	2.15	ns
t_{MCELL}	Macrocell Delay	—	0.65	—	0.75	—	0.85	ns
t_{INREG}	Input Buffer to Macrocell Register Delay	—	0.91	—	1.00	—	1.00	ns
t_{FBK}	Internal Feedback Delay	—	0.05	—	0.00	—	0.00	ns
t_{PDb}	5-PT Bypass Propagation Delay	—	0.40	—	0.40	—	0.40	ns
t_{PDi}	Macrocell Propagation Delay	—	0.25	—	0.25	—	0.65	ns
Register/Latch Delays								
t_{S}	D-Register Setup Time (Global Clock)	0.80	—	0.95	—	0.90	—	ns
t_{S_PT}	D-Register Setup Time (Product Term Clock)	1.35	—	1.95	—	1.90	—	ns
t_{ST}	T-Register Setup Time (Global Clock)	1.00	—	1.15	—	1.10	—	ns
t_{ST_PT}	T-register Setup Time (Product Term Clock)	1.55	—	1.75	—	2.10	—	ns
t_{H}	D-Register Hold Time	1.40	—	1.55	—	1.80	—	ns
t_{HT}	T-Resister Hold Time	1.40	—	1.55	—	1.80	—	ns
t_{SIR}	D-Input Register Setup Time (Global Clock)	0.94	—	0.90	—	1.50	—	ns
t_{SIR_PT}	D-Input Register Setup Time (Product Term Clock)	1.45	—	1.45	—	1.45	—	ns
t_{HIR}	D-Input Register Hold Time (Global Clock)	1.06	—	1.20	—	1.10	—	ns
t_{HIR_PT}	D-Input Register Hold Time (Product Term Clock)	0.88	—	1.00	—	1.00	—	ns
t_{COi}	Register Clock to Output/Feedback MUX Time	—	0.65	—	0.70	—	0.65	ns
t_{CES}	Clock Enable Setup Time	1.00	—	2.00	—	2.00	—	ns
t_{CEH}	Clock Enable Hold Time	0.00	—	0.00	—	0.00	—	ns
t_{SL}	Latch Setup Time (Global Clock)	0.80	—	0.95	—	0.90	—	ns
t_{SL_PT}	Latch Setup Time (Product Term Clock)	1.55	—	1.95	—	1.90	—	ns
t_{HL}	Latch Hold Time	1.40	—	1.80	—	1.80	—	ns
t_{GOi}	Latch Gate to Output/Feedback MUX Time	—	0.40	—	0.33	—	0.33	ns
t_{PDLi}	Propagation Delay through Transparent Latch to Output/ Feedback MUX	—	0.30	—	0.25	—	0.25	ns
t_{SRi}	Asynchronous Reset or Set to Output/Feedback MUX Delay	—	0.28	—	0.28	—	1.27	ns
t_{SRR}	Asynchronous Reset or Set Recovery Delay	—	2.00	—	1.67	—	1.80	ns
Control Delays								
t_{BCLK}	GLB PT Clock Delay	—	1.30	—	1.50	—	1.55	ns
t_{PTCLK}	Macrocell PT Clock Delay	—	1.50	—	1.70	—	1.55	ns
t_{BSR}	GLB PT Set/Reset Delay	—	1.10	—	1.83	—	1.83	ns
t_{PTSR}	Macrocell PT Set/Reset Delay	—	1.22	—	2.02	—	1.83	ns

ispMACH 4000Z Internal Timing Parameters (Cont.)

Over Recommended Operating Conditions

Parameter	Description	-35		-37		-42		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{GPTOE}	Global PT OE Delay	—	1.9	—	2.35	—	2.60	ns
t_{PTOE}	Macrocell PT OE Delay	—	2.4	—	3.35	—	2.60	ns

Note: Internal Timing Parameters are not tested and are for reference only. Refer to the timing model in this data sheet for further details.

Timing v.2.2

ispMACH 4000V/B/C Timing Adders[1] (Cont.)

Adder Type	Base Parameter	Description	-5		-75		-10		Units
			Min.	Max.	Min.	Max.	Min.	Max.	
Optional Delay Adders									
t_{INDIO}	t_{INREG}	Input register delay	—	1.00	—	1.00	—	1.00	ns
t_{EXP}	t_{MCELL}	Product term expander delay	—	0.33	—	0.33	—	0.33	ns
t_{ORP}	—	Output routing pool delay	—	0.05	—	0.05	—	0.05	ns
t_{BLA}	t_{ROUTE}	Additional block loading adder	—	0.05	—	0.05	—	0.05	ns
t_{IOI} Input Adjusters									
LVTTL_in	t_{IN}, t_{GCLK_IN}, t_{GOE}	Using LVTTL standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS33_in	t_{IN}, t_{GCLK_IN}, t_{GOE}	Using LVCMOS 3.3 standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS25_in	t_{IN}, t_{GCLK_IN}, t_{GOE}	Using LVCMOS 2.5 standard	—	0.60	—	0.60	—	0.60	ns
LVCMOS18_in	t_{IN}, t_{GCLK_IN}, t_{GOE}	Using LVCMOS 1.8 standard	—	0.00	—	0.00	—	0.00	ns
PCI_in	t_{IN}, t_{GCLK_IN}, t_{GOE}	Using PCI compatible input	—	0.60	—	0.60	—	0.60	ns
t_{IOO} Output Adjusters									
LVTTL_out	t_{BUF}, t_{EN}, t_{DIS}	Output configured as TTL buffer	—	0.20	—	0.20	—	0.20	ns
LVCMOS33_out	t_{BUF}, t_{EN}, t_{DIS}	Output configured as 3.3V buffer	—	0.20	—	0.20	—	0.20	ns
LVCMOS25_out	t_{BUF}, t_{EN}, t_{DIS}	Output configured as 2.5V buffer	—	0.10	—	0.10	—	0.10	ns
LVCMOS18_out	t_{BUF}, t_{EN}, t_{DIS}	Output configured as 1.8V buffer	—	0.00	—	0.00	—	0.00	ns
PCI_out	t_{BUF}, t_{EN}, t_{DIS}	Output configured as PCI compatible buffer	—	0.20	—	0.20	—	0.20	ns
Slow Slew	t_{BUF}, t_{EN}	Output configured for slow slew rate	—	1.00	—	1.00	—	1.00	ns

Note: Open drain timing is the same as corresponding LVCMOS timing. Timing v.3.2

1. Refer to TN1004, ispMACH 4000 Timing Model Design and Usage Guidelines for information regarding use of these adders.

ispMACH 4032V/B/C/Z and 4064V/B/C/Z Logic Signal Connections: 48-Pin TQFP (Cont.)

Pin Number	Bank Number	ispMACH 4032V/B/C/Z		ispMACH 4064V/B/C		ispMACH 4064Z	
		GLB/MC/Pad	ORP	GLB/MC/Pad	ORP	GLB/MC/Pad	ORP
33	1	B10	B^10	D4	D^2	D10	D^5
34	1	B11	B^11	D6	D^3	D8	D^4
35	-	TDO	-	TDO	-	TDO	-
36	-	VCC	-	VCC	-	VCC	-
37	-	GND	-	GND	-	GND	-
38	1	B12	B^12	D8	D^4	D6	D^3
39	1	B13	B^13	D10	D^5	D4	D^2
40	1	B14	B^14	D12	D^6	D2	D^1
41	1	B15/GOE1	B^15	D14/GOE1	D^7	D0/GOE1	D^0
42	1	CLK3/I	-	CLK3/I	-	CLK3/I	-
43	0	CLK0/I	-	CLK0/I	-	CLK0/I	-
44	0	A0/GOE0	A^0	A0/GOE0	A^0	A0/GOE0	A^0
45	0	A1	A^1	A2	A^1	A1	A^1
46	0	A2	A^2	A4	A^2	A2	A^2
47	0	A3	A^3	A6	A^3	A4	A^3
48	0	A4	A^4	A8	A^4	A6	A^4

ispMACH 4032Z and 4064Z Logic Signal Connections: 56-Ball csBGA

Ball Number	Bank Number	ispMACH 4032Z		ispMACH 4064Z	
		GLB/MC/Pad	ORP	GLB/MC/Pad	ORP
B1	-	TDI	-	TDI	-
C3	0	A5	A^5	A8	A^5
C1	0	A6	A^6	A10	A^6
D1	0	A7	A^7	A11	A^7
D3	0	GND (Bank 0)	-	GND (Bank 0)	-
E3	0	NC[1]	-	I[1]	-
E1	0	NC[1]	-	I[1]	-
F3	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-
F1	0	A8	A^8	B15	B^7
G3	0	A9	A^9	B12	B^6
G1	0	A10	A^10	B10	B^5
H1	0	A11	A^11	B8	B^4
J1	0	NC	-	I	-
K1	-	TCK	-	TCK	-
K2	-	VCC	-	VCC	-
H3	-	GND	-	GND	-
K3	-	NC[1]	-	I[1]	-
K4	0	A12	A^12	B6	B^3
H4	0	A13	A^13	B4	B^2
H5	0	A14	A^14	B2	B^1

ispMACH 4128V/B/C Logic Signal Connections: 128-Pin TQFP (Cont.)

Pin Number	Bank Number	ispMACH 4128V/B/C	
		GLB/MC/Pad	ORP
62	1	E10	E^8
63	1	E12	E^9
64	1	E14	E^11
65	1	GND	-
66	1	TMS	-
67	1	VCCO (Bank 1)	-
68	1	F0	F^0
69	1	F1	F^1
70	1	F2	F^2
71	1	F4	F^3
72	1	F5	F^4
73	1	F6	F^5
74	1	GND (Bank 1)	-
75	1	F8	F^6
76	1	F9	F^7
77	1	F10	F^8
78	1	F12	F^9
79	1	F13	F^10
80	1	F14	F^11
81	1	VCCO (Bank 1)	-
82	1	G14	G^11
83	1	G13	G^10
84	1	G12	G^9
85	1	G10	G^8
86	1	G9	G^7
87	1	G8	G^6
88	1	GND (Bank 1)	-
89	1	G6	G^5
90	1	G5	G^4
91	1	G4	G^3
92	1	G2	G^2
93	1	G0	G^0
94	1	VCCO (Bank 1)	-
95	1	TDO	-
96	1	VCC	-
97	1	GND	-
98	1	H14	H^11
99	1	H13	H^10
100	1	H12	H^9
101	1	H10	H^8
102	1	H9	H^7
103	1	H8	H^6
104	1	GND (Bank 1)	-

ispMACH 4128V and 4256V Logic Signal Connections: 144-Pin TQFP

Pin Number	Bank Number	ispMACH 4128V		ispMACH 4256V	
		GLB/MC/Pad	ORP	GLB/MC/Pad	ORP
1	-	GND	-	GND	-
2	-	TDI	-	TDI	-
3	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-
4	0	B0	B^0	C12	C^6
5	0	B1	B^1	C10	C^5
6	0	B2	B^2	C8	C^4
7	0	B4	B^3	C6	C^3
8	0	B5	B^4	C4	C^2
9	0	B6	B^5	C2	C^1
10	0	GND (Bank 0)	-	GND (Bank 0)	-
11	0	B8	B^6	D14	D^7
12	0	B9	B^7	D12	D^6
13	0	B10	B^8	D10	D^5
14	0	B12	B^9	D8	D^4
15	0	B13	B^10	D6	D^3
16	0	B14	B^11	D4	D^2
17	-	NC[2]	-	I[2]	-
18	0	GND (Bank 0)[1]	-	NC[1]	-
19	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-
20	0	NC[2]	-	I[2]	-
21	0	C14	C^11	E2	E^1
22	0	C13	C^10	E4	E^2
23	0	C12	C^9	E6	E^3
24	0	C10	C^8	E8	E^4
25	0	C9	C^7	E10	E^5
26	0	C8	C^6	E12	E^6
27	0	GND (Bank 0)	-	GND (Bank 0)	-
28	0	C6	C^5	F2	F^1
29	0	C5	C^4	F4	F^2
30	0	C4	C^3	F6	F^3
31	0	C2	C^2	F8	F^4
32	0	C1	C^1	F10	F^5
33	0	C0	C^0	F12	F^6
34	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-
35	-	TCK	-	TCK	-
36	-	VCC	-	VCC	-
37	-	GND	-	GND	-
38	0	NC[2]	-	I[2]	-
39	0	D14	D^11	G12	G^6
40	0	D13	D^10	G10	G^5
41	0	D12	D^9	G8	G^4
42	0	D10	D^8	G6	G^3

ispMACH 4256V/B/C/Z, 4384V/B/C, 4512V/B/C, Logic Signal Connections: 176-Pin TQFP (Cont.)

Pin Number	Bank Number	ispMACH 4256V/B/C/Z		ispMACH 4384V/B/C		ispMACH 4512V/B/C	
		GLB/MC/Pad	ORP	GLB/MC/Pad	ORP	GLB/MC/Pad	ORP
19	0	D4	D^2	E4	E^2	G4	G^2
20	0	D2	D^1	E2	E^1	G2	G^1
21	0	D0	D^0	E0	E^0	G0	G^0
22	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-	VCCO (Bank 0)	-
23	0	E0	E^0	H0	H^0	J0	J^0
24	0	E2	E^1	H2	H^1	J2	J^1
25	0	E4	E^2	H4	H^2	J4	J^2
26	0	E6	E^3	H6	H^3	J6	J^3
27	0	E8	E^4	H8	H^4	J8	J^4
28	0	E10	E^5	H10	H^5	J10	J^5
29	0	E12	E^6	H12	H^6	J12	J^6
30	0	E14	E^7	H14	H^7	J14	J^7
31	0	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-
32	0	F0	F^0	J0	J^0	N0	N^0
33	0	F2	F^1	J2	J^1	N2	N^1
34	0	F4	F^2	J4	J^2	N4	N^2
35	0	F6	F^3	J6	J^3	N6	N^3
36	0	F8	F^4	J8	J^4	N8	N^4
37	0	F10	F^5	J10	J^5	N10	N^5
38	0	F12	F^6	J12	J^6	N12	N^6
39	0	F14	F^7	J14	J^7	N14	N^7
40	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-	VCCO (Bank 0)	-
41	-	TCK	-	TCK	-	TCK	-
42	-	VCC	-	VCC	-	VCC	-
43	-	NC	-	NC	-	NC	-
44	-	NC	-	NC	-	NC	-
45	-	NC	-	NC	-	NC	-
46	-	GND	-	GND (Bank 0)	-	GND	-
47	0	G14	G^7	K14	K^7	O14	O^7
48	0	G12	G^6	K12	K^6	O12	O^6
49	0	G10	G^5	K10	K^5	O10	O^5
50	0	G8	G^4	K8	K^4	O8	O^4
51	0	G6	G^3	K6	K^3	O6	O^3
52	0	G4	G^2	K4	K^2	O4	O^2
53	0	G2	G^1	K2	K^1	O2	O^1
54	0	G0	G^0	K0	K^0	O0	O^0
55	0	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-
56	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-	VCCO (Bank 0)	-
57	0	H14	H^7	L14	L^7	P14	P^7
58	0	H12	H^6	L12	L^6	P12	P^6
59	0	H10	H^5	L10	L^5	P10	P^5

ispMACH 4256V/B/C, 4384V/B/C, 4512V/B/C Logic Signal Connections: 256-Ball ftBGA/fpBGA (Cont.)

Ball Number	I/O Bank	ispMACH 4256V/B/C 128-I/O		ispMACH 4256V/B/C 160-I/O		ispMACH 4384V/B/C		ispMACH 4512V/B/C	
		GLB/MC/Pad	ORP	GLB/MC/Pad	ORP	GLB/MC/Pad	ORP	GLB/MC/Pad	ORP
C12	1	O0	O^0	O2	O^2	GX0	GX^0	OX0	OX^0
E10	1	NC	-	O1	O^1	CX8	CX^4	MX0	MX^0
A13	1	NC	-	O0	O^0	CX10	CX^5	MX4	MX^1
D12	1	NC	-	NC	-	NC	-	LX0	LX^0
-	1	GND (Bank 1)	-	GND (Bank 1)	-	GND (Bank 1)	-	GND (Bank 1)	-
-	1	VCCO (Bank 1)	-	VCCO (Bank 1)	-	VCCO (Bank 1)	-	VCCO (Bank 1)	-
B12	1	NC	-	NC	-	NC	-	LX4	LX^1
A12	1	NC	-	NC	-	EX2	EX^1	LX8	LX^2
B11	1	NC	-	NC	-	EX0	EX^0	LX12	LX^3
A11	1	NC	-	P14	P^9	CX12	CX^6	MX8	MX^2
D10	1	NC	-	P12	P^8	CX14	CX^7	MX12	MX^3
C10	1	P14	P^7	P10	P^7	HX14	HX^7	PX14	PX^7
B10	1	P12	P^6	P9	P6	HX12	HX^6	PX12	PX^6
A10	1	P10	P^5	P8	P^5	HX10	HX^5	PX10	PX^5
A9	1	P8	P^4	P6	P^4	HX8	HX^4	PX8	PX^4
F9	1	P6	P^3	P4	P^3	HX6	HX^3	PX6	PX^3
B9	1	P4	P^2	P2	P^2	HX4	HX^2	PX4	PX^2
E9	1	P2/GOE1	P^1	P1/GOE1	P^1	HX2/GOE1	HX^1	PX2/GOE1	PX^1
C9	1	P0	P^0	P0	P^0	HX0	HX^0	PX0	PX^0
-	-	GND	-	GND		GND	-	GND	-
D9	1	CLK3/I	-	CLK3/I	-	CLK3/I	-	CLK3/I	-
-	0	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-
B8	0	CLK0/I	-	CLK0/I	-	CLK0/I	-	CLK0/I	-
-	-	VCC	-	VCC	-	VCC	-	VCC	-
D8	0	A0	A^0	A0	A^0	A0	A^0	A0	A^0
C8	0	A2/GOE0	A^1	A1/GOE0	A^1	A2/GOE0	A^1	A2/GOE0	A^1
A8	0	A4	A^2	A2	A^2	A4	A^2	A4	A^2
A7	0	A6	A^3	A4	A^3	A6	A^3	A6	A^3
B7	0	A8	A^4	A6	A^4	A8	A^4	A8	A^4
E8	0	A10	A^5	A8	A^5	A10	A^5	A10	A^5
D7	0	A12	A^6	A9	A^6	A12	A^6	A12	A^6
F8	0	A14	A^7	A10	A^7	A14	A^7	A14	A^7
C7	0	NC	-	A12	A^8	F14	F^7	D0	D^0
A6	0	NC	-	A14	A^9	F12	F^6	D4	D^1
B6	0	NC	-	NC	-	D14	D^7	E0	E^0
A5	0	NC	-	NC	-	D12	D^6	E4	E^1
B5	0	NC	-	NC	-	NC	-	E8	E^2
-	0	VCCO (Bank 0)	-	VCCO (Bank 0)	-	VCCO (Bank 0)	-	VCCO (Bank 0)	-
-	0	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-	GND (Bank 0)	-
D5	0	NC	-	NC	-	NC	-	E12	E^3
A4	0	NC	-	B0	B^0	F10	F^5	D8	D^2

ispMACH 4000V (3.3V) Extended Temperature Devices

Device	Part Number	Macrocells	Voltage	t_{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032V	LC4032V-75T48E	32	3.3	7.5	TQFP	48	32	E
	LC4032V-75T44E	32	3.3	7.5	TQFP	44	30	E
LC4064V	LC4064V-75T100E	64	3.3	7.5	TQFP	100	64	E
	LC4064V-75T48E	64	3.3	7.5	TQFP	48	32	E
	LC4064V-75T44E	64	3.3	7.5	TQFP	44	30	E
LC4128V	LC4128V-75T144E	128	3.3	7.5	TQFP	144	96	E
	LC4128V-75T128E	128	3.3	7.5	TQFP	128	92	E
	LC4128V-75T100E	128	3.3	7.5	TQFP	100	64	E
LC4256V	LC4256V-75T176E	256	3.3	7.5	TQFP	176	128	E
	LC4256V-75T144E	256	3.3	7.5	TQFP	144	96	E
	LC4256V-75T100E	256	3.3	7.5	TQFP	100	64	E

ispMACH 4000V (3.3V) Lead-Free Extended Temperature Devices

Device	Part Number	Macrocells	Voltage	t_{PD}	Package	Pin/Ball Count	I/O	Grade
LC4032V	LC4032V-75TN48E	32	3.3	7.5	Lead-free TQFP	48	32	E
	LC4032V-75TN44E	32	3.3	7.5	Lead-free TQFP	44	30	E
LC4064V	LC4064V-75TN100E	64	3.3	7.5	Lead-free TQFP	100	64	E
	LC4064V-75TN48E	64	3.3	7.5	Lead-free TQFP	48	32	E
	LC4064V-75TN44E	64	3.3	7.5	Lead-free TQFP	44	30	E
LC4128V	LC4128V-75TN144E	128	3.3	7.5	Lead-free TQFP	144	96	E
	LC4128V-75TN128E	128	3.3	7.5	Lead-free TQFP	128	92	E
	LC4128V-75TN100E	128	3.3	7.5	Lead-free TQFP	100	64	E
LC4256V	LC4256V-75TN176E	256	3.3	7.5	Lead-free TQFP	176	128	E
	LC4256V-75TN144E	256	3.3	7.5	Lead-free TQFP	144	96	E
	LC4256V-75TN100E	256	3.3	7.5	Lead-free TQFP	100	64	E

For Further Information

In addition to this data sheet, the following technical notes may be helpful when designing with the ispMACH 4000V/B/C/Z family:

- TN1004, ispMACH 4000 Timing Model Design and Usage Guidelines
- TN1005, Power Estimation in ispMACH 4000V/B/C/Z Devices

Revision History

Date	Version	Change Summary
—	—	Previous Lattice releases.
July 2003	17z	Changed device status for LC4064ZC and LC4128ZC to production release and updated/added AC and DC parameters as well as ordering part numbers for LC4064ZC and LC4128ZC devices.
		Improved leakage current specifications for ispMACH 4000Z. For ispMACH 4000V/B/C IIL, IIH condition now includes 0V and 3.6V end points (0 ≤ VIN ≤ 3.6V).
		Added 132-ball chip scale BGA power supply and NC connections.
		Added 132-ball chip scale BGA logic signal connections for LC4064ZC, LC4128ZC and LC4256ZC devices.
		Added lead-free package designators.
October 2003	18z	Hot socketing characteristics footnote 1. has been enhanced; Insensitive to sequence of VCC or VCCO. However, assumes monotonic rise/fall rates for Vcc and Vcco, provided (VIN - VCCO) ≤ 3.6V.
		Improved LC4064ZC t_S to 2.5ns, t_{ST} to 2.7ns and f_{MAX} (Ext.) to 175MHz, LC4128ZC t_{CO} to 3.5ns and f_{MAX} (Ext.) to 161MHz (version v.2.1).
		Improved associated internal timing numbers and timing adders (version v.2.1).
		Added ispMACH 4000V/B/C/Z ORP Reference Tables.
		Enhanced ORP information in device pinout tables consistent with the ORP Combinations for I/O Blocks tables (table 6, 7, 8 and 9 in page 9-11).
		Corrected GLB/MC/Pad information in the 256-fpBGA pinouts for the LC4256V/B/C 160-I/O version.
		Added the ispMACH 4000 Family Speed Grade Offering table.
		Added the ispMACH 4128ZC Industrial and Automotive Device OPNs
December 2003	19z	Added the ispMACH 4032ZC and 4064ZC Industrial and Automotive Device OPNs